## Investigation on structural, morphological, electronic and photovoltaic properties of perovskite thin film by introducing lithium halide

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Figure S1. Zoom-in XRD spectra for perovskite thin films with different molar doping ratios of LiI.



Figure S2. XRD spectra of perovskite thin films with different molar doping ratios of LiBr.



Figure S3. The band gap of Li doped perovskite as a function of doping ratio.



**Figure S4**. Steady-state PCE output of the devices at maximum power point of pristine and Li doped perovskite devices.